

# Ritish Behera

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<b>EXPERIENCE</b>	<b>Summer Research Intern</b> IIT Gandhinagar, Gujarat May-july 2023 <b>Topic- "Circuit Simulation of Heterogeneous 6T SRAM Featuring MoS2-FET based Pass Transistor"</b> The research work involved designing of a heterogeneous 6T SRAM cell consisting of Si cross-coupled inverter on the FEOL level and MoS2-FET based pass transistor to be implemented on the BEOL level. Using cadence virtuoso tool, I carried out circuit simulations for noise margin (read, write and hold) calculation of the hybrid cell and further explored some potential solutions for interconnect and parasitic modelling to describe the integration.
<b>PROJECTS</b>	<b>Noise Margin Analysis of Different Si &amp; MoS2 FET based SRAM Architectures</b> (On-going) Design of various SRAM cells architectures (6T, NTV 7T, Single Bitline 7T, Read-Assited 7T, 9T & 10T) using both Si and MoS2 based mosfet devices and hence calculating their noise margin response. Tool Used- Cadence Virtuoso. Process node- GPDK 180nm.  <b>Traditional and Thin Cell Layout Design of 6T SRAM Cell</b> Replicated the layout design of traditional and thin cell SRAM cells using Virtuoso Layout XL environment with successful DRC and LVS checks. Process node- 180nm.  <b>Design and Analysis of SRAM Cell in Latest UMC 28nm Technology</b> Done simulations for transient, DC and noise margin analysis of 6T SRAM cell followed by static and dynamic power consumption using the latest UMC28nm technology (Tool used- Virtuoso ADE L)  <b>Triboelectric Nanogenerator Circuit Modelling Using SIMULINK</b> Modeled the appropriate circuit of the TENG device using SIMULINK, for further simulations of the device characteristics
<b>SKILLS</b>	<b>EDA Tools:</b> Cadence Virtuoso, Sentaurus TCAD, OpenRoad, Xilinx Vivado, DEEDs <b>Languages:</b> Verilog, Assembly, Perl, C++, MATLAB <b>Environment:</b> Windows, Linux (Ubuntu). <b>Hands-on:</b> 8086 Microprocessor, Artix-7 Power FPGA board
<b>INTERESTS</b>	Physical Design (PR, PSV, Layout), Memory Devices, Interconnect & Parasitic Modelling, Computer Architecture, Industrial R&D
<b>CERTIFICATION COURSES</b>	<b>VLSI Physical Design with STA</b> NPTEL, Apr 2024 <b>Digital IC Design</b> NPTEL, Apr 2024 <b>VLSI Design Flow: RTL to GDS</b> NPTEL, Dec 2023 <b>Semiconductor Device Modelling and Simulations</b> NPTEL, Apr 2023

<b>EDUCATION</b>	<b>MSc(Tech) Engineering Physics (Electronics Specialization)</b>	GPA: 7.25
	<b>NIT Warangal, Telangana</b>	<b>2022-25</b>
	Relevant Courses: VLSI Technology, Microprocessor & Interfacing, Computer Organization, Digital Electronics (STLD & SDSD), Linear Integrated Circuits, Electronic Devices and Circuits, Material Science, Solid State Physics	
	<b>BSc Physics Honors</b>	GPA: 8.2
	<b>Gangadhar Meher University, Odisha</b>	<b>2018-21</b>
	Relevant Courses: Digital Circuits, Analog Circuits, Device Physics, Solid State Physics	
<b>EXTRA-CURRICULAR</b>	<b>Joint Secretary</b> , Physics Association, NIT Warangal	2022-23
	<b>Executive Member</b> , NSS, NIT Warangal	2022-23